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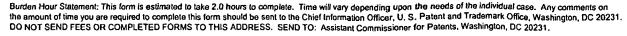
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Application Number	10/002,461	
Filing Date	November 1, 2001	
First Named Inventor	Keith R. Slavin	
Group Art Unit	2187	
Examiner Name	R. ELMORE	
Attorney Docket Number	DB000955-000	

			U.S. PATENT DO	CUMENTS	
Examiner Initials	Cite No.1	U.S. Patent Docum Number  Kind	Name of Patentee or Applicar of Cited Document	MM-DD-YYYY	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
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